

# Isolated Drive Transmitter

## FEATURES

- 500mA Output Drive, Source or Sink
- 8 to 35V Operation
- Transmits Logic Signal Instantly
- Programmable Operating Frequency
- Under-Voltage Lockout
- Able To Pass DC Information Across Transformer
- Up To 600kHz Operation

## DESCRIPTION

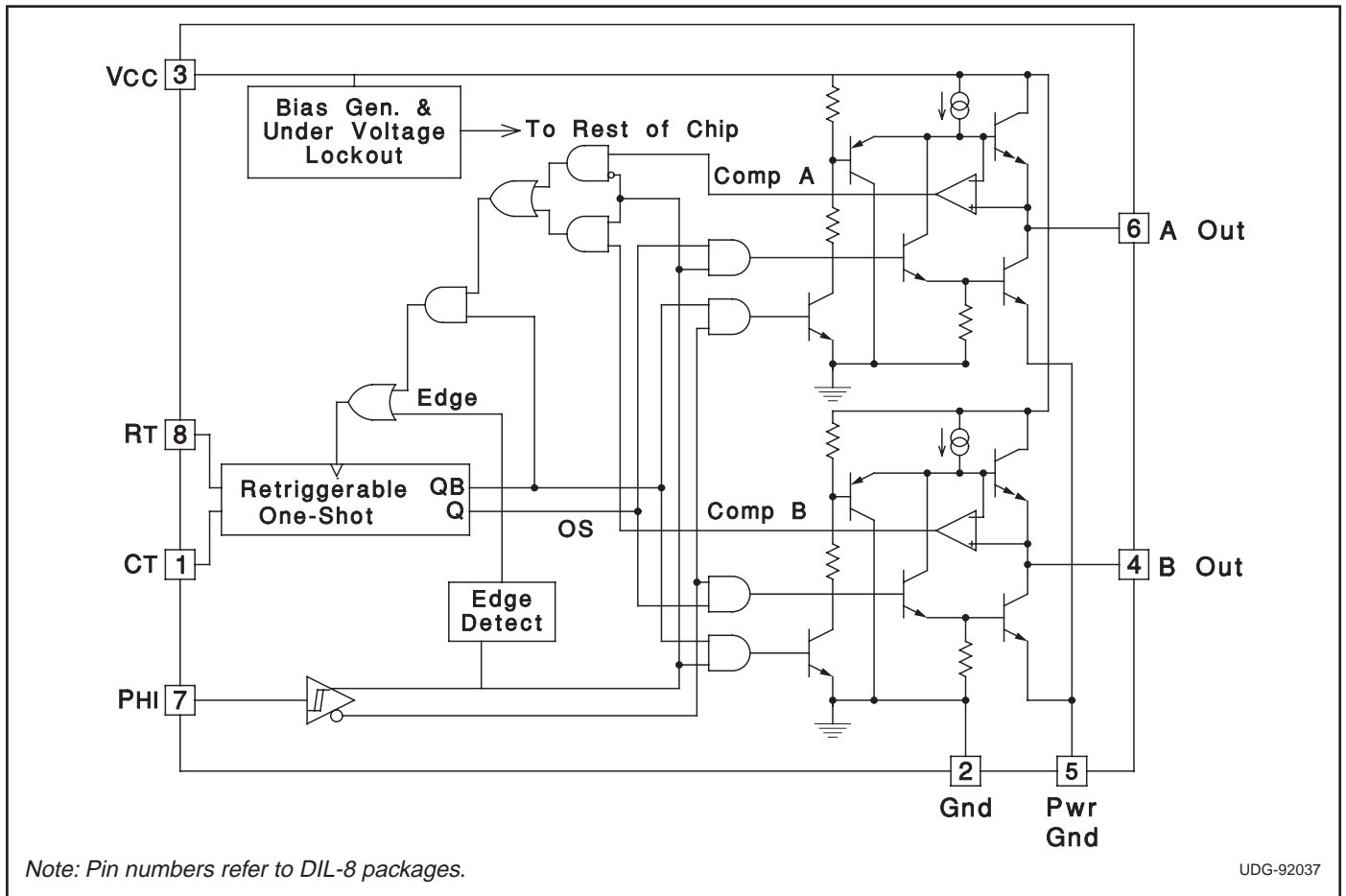
The UC1724 family of Isolated Drive Transmitters, along with the UC1725 Isolated Drivers, provide a unique solution to driving isolated power MOSFET gates. They are particularly suited to drive the high-side devices on a high-voltage H-bridge. The UC1724 devices transmit drive logic, and drive power, to the isolated gate circuit using a low cost pulse transformer.

This drive system utilizes a duty-cycle modulation technique that gives instantaneous response to the drive control transistions, and reliably passes steady-state, or DC, conditions. High frequency operation, up to 600kHz, allows the cost and size of the coupling transformer to be minimized.

These devices will operate over an 8 to 35 Volt supply range. The dual high current totem pole outputs are disabled by an under-voltage lockout circuit to prevent spurious responses during startup or low voltage conditions.

These devices are available in 8 pin plastic or ceramic dual-inline packages, as well as 16 pin SOIC package.

## BLOCK DIAGRAM



### ABSOLUTE MAXIMUM RATINGS

Supply Voltage  $V_{IN}$  . . . . . 40V  
 Source/Sink Current (Pulsed) . . . . . 1A  
 Source/Sink Current (Continuous) . . . . . 0.5A  
 Output Voltage (Pins 4, 6) . . . . .  $-0.3$  to  $(V_{IN} + 0.3)$ V  
 $\Phi_{HI}$ ,  $R_T$ , and  $C_T$  inputs (Pins 1, 7, and 8) . . . . .  $-0.3$  to 6V  
 Operating Junction Temperature (Note 2) . . . . . 150°C  
 Storage Temperature Range . . . . .  $-65^\circ\text{C}$  to 150°C  
 Lead Temperature (Soldering, 10 Seconds) . . . . . 300°C

- Note 1:** All voltages are with respect to GND (Pin 2); all currents are positive into, negative out of part.  
**Note 2:** Consult Unitorde Integrated Circuit Databook for thermal limitations and considerations of package.  
**Note 3:** Pin numbers refer to DIL-8 packages.

### RECOMMENDED OPERATION CONDITIONS

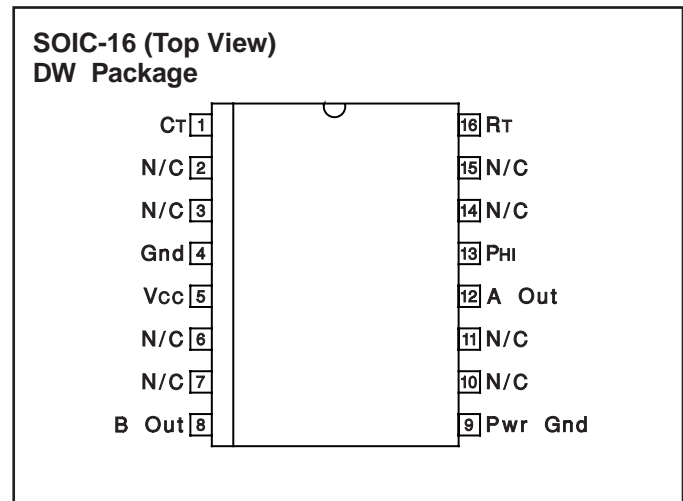
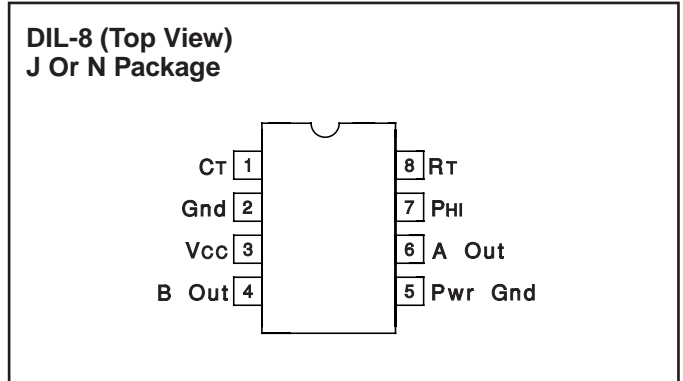
Input Voltage . . . . . +9V to +35V  
 Sink/Source Load Current (each output) . . . . . 0 to 500mA  
 Timing Resistor . . . . . 2k $\Omega$  to 10k $\Omega$   
 Timing Capacitor . . . . . 300pF to 3nF  
 Operating Temperature Range (UC1724) . . . . .  $-55^\circ\text{C} < T_A < 125^\circ\text{C}$   
 Operating Temperature Range (UC3724) . . . . .  $0^\circ\text{C} < T_A < 70^\circ\text{C}$

**Note 4:** Range over which the device is functional and parameter limits are guaranteed.

### ORDERING INFORMATION

	TEMPERATURE RANGE	PACKAGE
UC1724J	$-55^\circ\text{C}$ to $+125^\circ\text{C}$	CDIP
UC2724DW	$-25^\circ\text{C}$ to $+85^\circ\text{C}$	SOIC-Wide
UC2724N		PDIP
UC3724DW	$0^\circ\text{C}$ to $+70^\circ\text{C}$	SOIC-Wide
UC3724N		PDIP

### CONNECTION DIAGRAMS



**ELECTRICAL CHARACTERISTICS:** Unless otherwise stated,  $V_{CC} = 20\text{V}$ ,  $R_T = 4.3\text{k}\Omega$ ,  $C_T = 1000\text{pF}$ , no load on any output and these specifications apply for:  $-55^\circ\text{C} < T_A < 125^\circ\text{C}$  for the UC1724,  $-25^\circ\text{C} < T_A < 85^\circ\text{C}$  for the UC2724, and  $0^\circ\text{C} < T_A < 70^\circ\text{C}$  for the UC3724.  $T_A = T_J$ .

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>Under-Voltage Lockout</b>					
Start-Up Threshold	$V_{IN}$ Rising		7.75	9.5	V
Threshold Hysteresis		0.4	1.0	1.5	V
<b>Retriggerable One-Shot</b>					
Initial Accuracy	$T_J = 25^\circ\text{C}$	1.54	1.9	2.25	$\mu\text{s}$
Temperature Stability	Over Operating $T_J$	1.0		2.9	$\mu\text{s}$
Voltage Stability	$V_{IN} = 10$ to 35V		0.2	0.5	%/V
Operating Frequency	$L_{LOAD} = 1.4\text{mH}$	100	150	200	kHz
Minimum Pulse Width	$R_T = 2\text{k}$ $C_T = 300\text{pF}$	100	500	1200	ns
Operating Frequency	$R_T = 2\text{k}$ $C_T = 300\text{pF}$ $L_{LOAD} = 1.4\text{mH}$	500	750	1100	kHz

**ELECTRICAL CHARACTERISTICS:** Unless otherwise stated,  $V_{CC} = 20V$ ,  $R_T = 4.3k\Omega$ ,  $C_T = 1000pF$ , no load on any output and these specifications apply for:  $-55^{\circ}C < T_A < 125^{\circ}C$  for the UC1724,  $-25^{\circ}C < T_A < 85^{\circ}C$  for the UC2724, and  $0^{\circ}C < T_A < 70^{\circ}C$  for the UC3724.  $T_A = T_J$ .

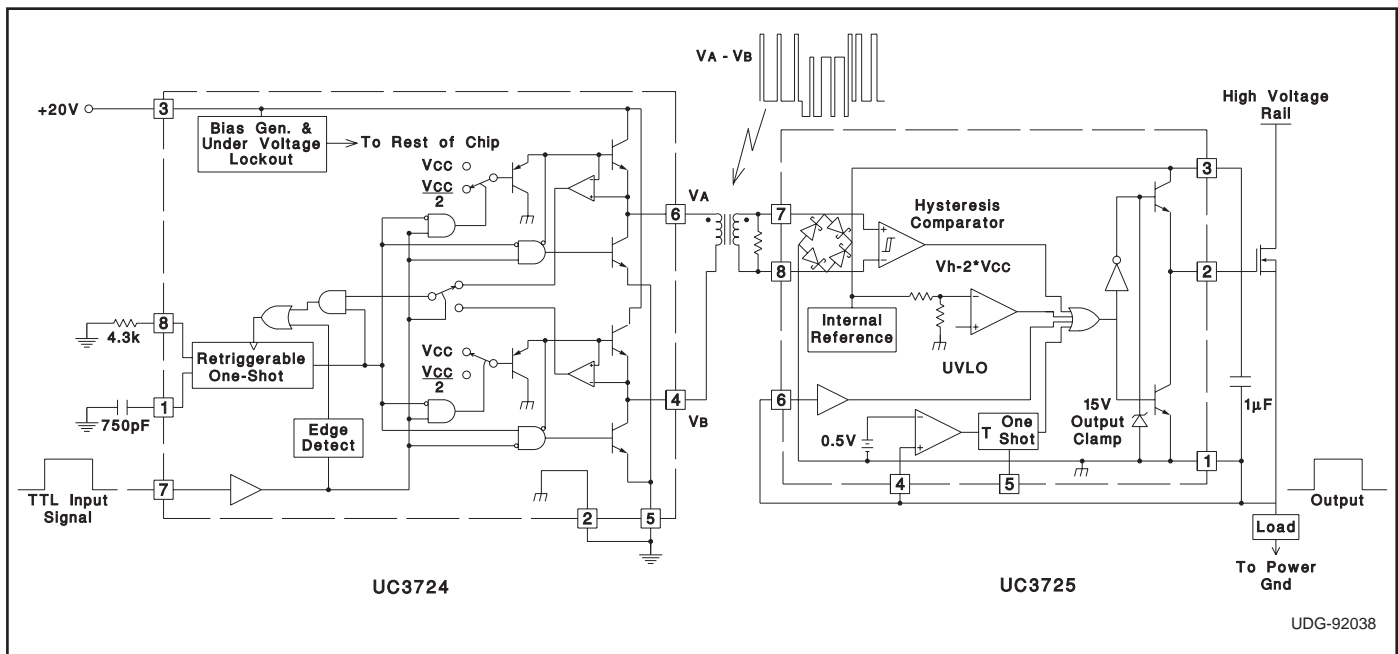
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
<b>Phi Input (Control Input)</b>					
HIGH Input Voltage		2.0			V
LOW Input Voltage				0.8	V
HIGH Input Current	$V_{IH} = +2.4V$	-220	-130		$\mu A$
LOW Input Current	$V_{IL} = +0.4V$	-600	-300		$\mu A$
Delay to One-Shot				350	ns
Delay to Output				250	ns
<b>Output Drivers</b>					
Output Low Level	$I_{SINK} = 50mA$		0.3	0.4	V
	$I_{SINK} = 250mA$		0.5	2.1	V
Output High Level (Volts Below $V_{CC}$ )	$I_{SOURCE} = 50 mA$		1.5	2.1	V
	$I_{SOURCE} = 250 mA$		1.7	2.5	V
Rise/Fall Time	No load		30	90	ns
<b>Total Supply Current</b>					
Supply Current	$C_T = 1.4V$		15	30	mA

**Additional Information**

Please refer to the following Unitorde application topics.

[1] Application Note U-127, *Unique Chip Pair Simplified Isolated High-Side Switch Drive* by John A. O'Connor.

[2] Design Note DN-35, *IGBT Drive Using MOSFET Gate Drivers* by John A. O'Conner.



**Figure 1. Typical application**

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